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Silicon PNP Power Transistor

2SA1146

DESCRIPTION

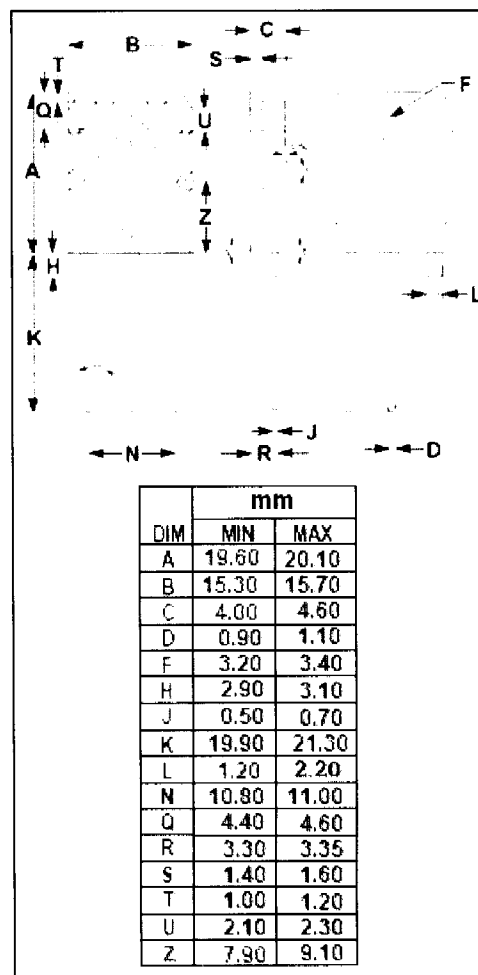
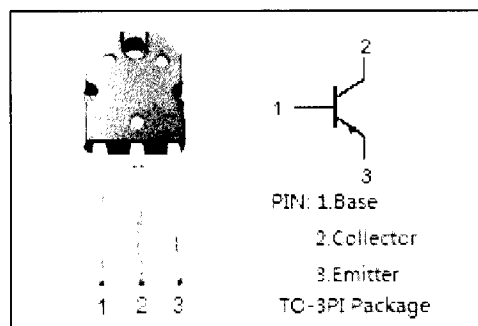
- Collector-Emitter Breakdown Voltage-
: $V_{(BR)CEO} = -140V(\text{Min})$
- Complement to Type 2SC2706

APPLICATIONS

- Audio frequency low power amplifier applications
- Recommend for 70W audio frequency amplifier output stage applications

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	-140	V
V_{CEO}	Collector-Emitter Voltage	-140	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current-Continuous	-10	A
I_B	Base Current-Continuous	-1	A
P_C	Collector Power Dissipation @ $T_c=25^\circ\text{C}$	100	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-55~150	$^\circ\text{C}$



NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

Quality Semi-Conductors

Silicon PNP Power Transistor**2SA1146****ELECTRICAL CHARACTERISTICS** $T_C=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = -50\text{mA}$; $I_B = 0$	-140			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -5\text{A}$; $I_B = -0.5\text{A}$			-2.0	V
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C = -5\text{A}$; $V_{CE} = -5\text{V}$			-2.5	V
I_{CBO}	Collector Cutoff Current	$V_{CB} = -140\text{V}$; $I_E = 0$			-50	μA
I_{EBO}	Emitter Cutoff Current	$V_{EB} = -5\text{V}$; $I_C = 0$			-50	μA
h_{FE-1}	DC Current Gain	$I_C = -1\text{A}$; $V_{CE} = -5\text{V}$	55		240	
h_{FE-2}	DC Current Gain	$I_C = -5\text{A}$; $V_{CE} = -5\text{V}$	30			
C_{OB}	Output Capacitance	$I_E = 0$; $V_{CB} = -10\text{V}$; $f_{test} = 1.0\text{MHz}$		220		pF
f_T	Current-Gain—Bandwidth Product	$I_C = -1\text{A}$; $V_{CE} = -10\text{V}$		70		MHz

◆ **h_{FE-1} Classifications**

R	O	Y
55-110	80-160	120-240